NSN 5961-01-349-0236

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-0236 **Inclosure Material:** Glass **Overall Length:** Between 0.360 inches and 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.190 inches and 0.205 inches **Function For Which Designed:** Bidirectional and transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 270.0 breakdown voltage, dc and 330.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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